

4 CHANNEL LOW CAPACITANCE TVS DIODE ARRAY

Product Summary

VBR (MIN)	IPP (MAX)	CI/O (TYP)
5.5V	5	0.5pF

Description

The D3V3F4U10LPQ is a high-performance device suitable for protecting four high speed I/Os. These devices are assembled in U-DFN2510-10 package and have high ESD surge capability, low ESD clamping voltage and ultra-low capacitance.

Applications

Typically used at high-speed ports such as USB 3.0, USB 3.1, Serial ATA, Display port.

Features

- Clamping Voltage: 5V at 16A IEC61000-4-2
- IEC61000-4-2 (ESD): Air ±12kV, Contact ±12kV
- IEC61000-4-5 (Lightning): 5A (8/20μs)
- 4 Channels of ESD Protection
- Ultra-Low Chanel Input Capacitance of 0.5pF Typical
- TLP Dynamic Resistance: 0.25Ω
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The D3V3F4U10LPQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

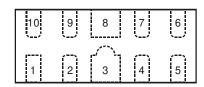
https://www.diodes.com/quality/product-definitions/

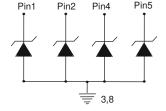
Mechanical Data

- Case: U-DFN2510-10
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: NiPdAu over Copper Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.038 grams (Approximate)

U-DFN2510-10

Pin#	Description
1, 2, 4, 5	I/O
6, 7, 9, 10	No Connection
3, 8	Vss





Pin Description (Top View)

Device Schematic

Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
D3V3F4U10LPQ-7	Automotive	QD6	7	8	3,000/Tape & Reel

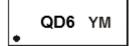
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Option A:



QD6 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021) M = Month (ex: 9 = September) Dot Denotes Cathode Side

Date Code Key:

Year	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code		J	K	L	М	N	0	Р	R	S	Т	U
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Option B:



QD6 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 1 = 2021)

Y = Year (ex: 1 = 2021) W = Week (ex: a = Week 27; z Represents Week 52 and 53)

X = Internal Code (ex: U = Monday)

Dot Denotes Cathode Side

Date Code Key

Year	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	1	2	3	4	5	6	7	8	9	0	1	2
Week	1-26			27-52				53				
Code	A-Z			a-z			Z					

Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat
Code	T	U	V	W	X	Υ	Z

Characteristic	Symbol	Value	Unit	Condition
Peak Pulse Current, per IEC61000-4-5	lpp	5	Α	I/O to V _{SS} , 8/20μs
Peak Pulse Power, per IEC61000-4-5	P _{PP}	30	W	I/O to Vss, 8/20μs
ESD Protection – Contact Discharge, per IEC61000-4-2	Vesd_contact	±12	kV	I/O to Vss
ESD Protection – Air Discharge, per IEC61000-4-2	Vesd_air	±12	kV	I/O to Vss

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation Typical (Note 5)	PD	350	mW
Thermal Resistance, Junction to Ambient Typical (Note 5)	$R_{ heta JA}$	360	°C/W
Operating and Storage Temperature Range	T _J ,T _{STG}	-55 to +150	°C

Note: 5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's suggested pad layout, which can be found on our website at http://www.diodes.com/package-outlines.html.

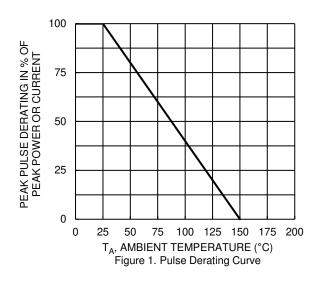


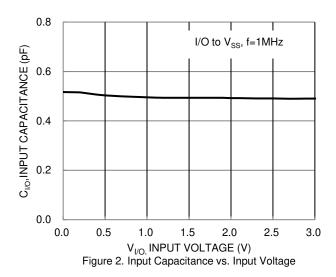
Electrical Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

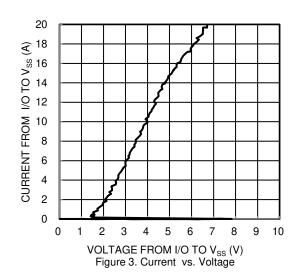
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}	_	_	3.3	V	_
Reverse Current	lR	_	_	1.0	μΑ	$V_R = 3.3V$, I/O to V_{SS}
Reverse Breakdown Voltage	V_{BR}	5.5	6.2	_	V	$I_R = 1 \text{mA}$, I/O to V_{SS}
Forward Clamping Voltage	VF	-1.0	-0.85	_	V	IF = -15mA, I/O to Vss
Holding Reverse Voltage	VHOLD	_	1.3	_	٧	I/O to Vss
Reverse Clamping Voltage (Note 6)	Vc	_	3.5	_	V	$I_{PP} = 5A$, I/O to V_{SS} , 8/20 μ s
Clamping Voltage (Note 7)	Vc	_	5	_	V	TLP, 16A, $t_P = 100$ ns, I/O to V_{SS}
Clamping Voltage (Note 7)	V _C	_	5	_	V	TLP, -16A, $t_P = 100$ ns, I/O to V_{SS}
Dynamic Reverse Resistance	Rdif-R	_	0.25	_	Ω	TLP, 10A, t _P = 100ns, I/O to V _{SS}
Dynamic Forward Resistance	R _{DIF-F}	_	0.2	_	Ω	TLP, 10A, $t_P = 100$ ns, V_{SS} to I/O
Channel Input Capacitance	CI/O	_	0.5	_	pF	$V_{I/O} = 0V$, $V_{SS} = 0V$, $f = 1MHz$

Notes:

- 6. Clamping voltage value is based on an 8x20µs peak pulse current (IPP) waveform.
- 7. Clamping voltage value is based on a TLP model. TLP conditions: $Z_0=50\Omega$, $t_P=100$ ns, $t_P=1$ ns, averageing window; $t_1=70$ ns to $t_2=90$ ns.





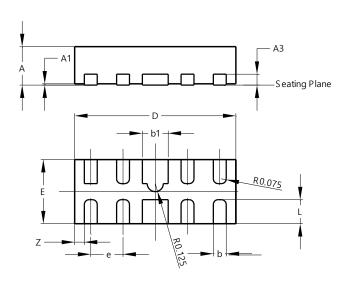




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2510-10

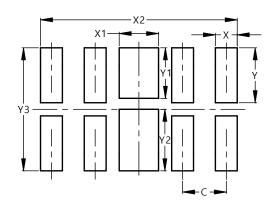


U-DFN2510-10								
Dim	Min	Max	Тур					
Α	0.545	0.605	0.575					
A 1	0.00	0.05	0.03					
A3	-	-	0.13					
b	0.15	0.25	0.20					
b1	035	0.45	0.40					
D	2.450	2.575	2.500					
е	-	-	0.50					
Е	0.950	1.075	1.000					
L	0.325	0.425	0.375					
Z	-	-	0.150					
All Dimensions in mm								

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2510-10



Dimensions	Value			
Dillielisions	(in mm)			
С	0.500			
X	0.250			
X1	0.450			
X2	2.250			
Υ	0.625			
Y1	0.575			
Y2	0.700			
Y3	1.400			



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